

Product Preview
Multiplexer - Demultiplexer

The MC74VHC1GT53 is an advanced high speed CMOS multiplexer – demultiplexer analog switch fabricated with silicon gate CMOS technology. It achieves high speed propagation delays and low ON resistances while maintaining CMOS low power dissipation. This multiplexer – demultiplexer controls analog and digital voltages that may vary across the full power-supply range (from V_{CC} to GND).

The MC74VHC1GT53 is compatible in function to a single gate of the High Speed CMOS MC74VHC4053. The device has been designed so that the ON resistances (R_{ON}) are much lower and more linear over input voltage than R_{ON} of the metal-gate CMOS analog switches.

The device input is compatible with TTL-type input thresholds allowing the device to be used as a logic-level translator from 3.0V CMOS logic to 5.0V CMOS Logic or from 1.8V CMOS logic to 3.0V CMOS Logic while operating at the higher-voltage power supply. The input protection circuitry on this device allows overvoltage tolerance on the input, which provides protection when voltages of up to 7V are applied, regardless of the supply voltage. This allows the MC74VHC1GT53 to be used to interface 5V circuits to 3V circuits.

- Low Power Dissipation: $I_{CC} = 2 \mu A$ (Max) at $T_A = 25^\circ C$
- Improved Linearity and Lower ON Resistance over Input Voltage
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V; MM > 200 V, CDM > 1500 V

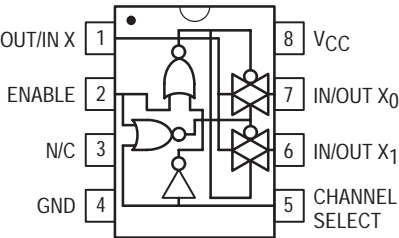
MC74VHC1GT53



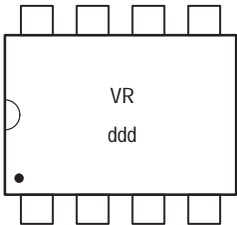
PLANNED PACKAGE
8-LEAD MICRO 8 PACKAGE
 $T_{amb} = -55^\circ C$ to $125^\circ C$

FUNCTION TABLE

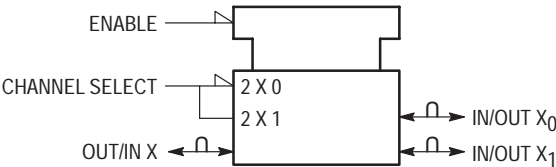
| Enable | Select | ON Channel |
|--------|--------|----------------|
| L | L | X ₀ |
| L | H | X ₁ |
| H | X | NONE |



PIN ASSIGNMENT



MARKING DIAGRAM
d = date code



LOGIC SYMBOL

DEVICE ORDERING INFORMATION

| Device Order Number | Device Nomenclature | | | | | | Package Type | Tape and Reel Size |
|---------------------|----------------------------|-----------------------|------------|-----------------|----------------|----------------------|--------------|--------------------|
| | Motorola Circuit Indicator | Temp Range Identifier | Technology | Device Function | Package Suffix | Tape and Reel Suffix | | |
| MC74VHC1GT53DMT1 | MC | 74 | VHC1G | T53 | DM | R2 | Micro 8 | 13-Inch/4000 Unit |

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.



ABSOLUTE MAXIMUM RATINGS

Maximum ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

| Characteristics | Symbol | Value | Unit |
|---|-----------|------------------------|------|
| DC Supply Voltage | V_{CC} | -0.5 to +7.0 | V |
| Digital Input Voltage | V_{IN} | -0.5 to $V_{CC} + 0.5$ | V |
| Analog Input Voltage | V_{IS} | -0.5 to $V_{CC} + 0.5$ | V |
| Digital Input Diode Current | I_{IK} | -20 | mA |
| DC Supply Current, V_{CC} and GND | I_{CC} | ± 25 | mA |
| Power dissipation in still air, Micro-8 † | P_D | 300 | mW |
| Lead temperature, 1 mm from case for 10 s | T_L | 260 | °C |
| Storage temperature | T_{stg} | -65 to +150 | °C |

† Power Dissipation Derating: Micro-8 Package: - 4.4 mW/°C from 65°C to 125°C

RECOMMENDED OPERATING CONDITIONS

| Characteristics | Symbol | Min | Max | Unit |
|--|------------|--------|-----------|------|
| DC Supply Voltage | V_{CC} | 2.0 | 5.5 | V |
| Digital Input Voltage | V_{IN} | GND | V_{CC} | V |
| Analog Input Voltage | V_{IS} | GND | V_{CC} | V |
| Static or Dynamic Voltage Across Switch | V_{IO}^* | — | 100 | mV |
| Operating Temperature Range | T_A | -55 | +125 | °C |
| Input Rise and Fall Time, SELECT & ENABLE $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | t_r, t_f | 0 0 | 100 20 | ns/V |

* For voltage drops across the switch greater than 100 mV (switch on), excessive V_{CC} current may be drawn; i.e. the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = 25°C | | | T _A ≤ 85°C | | T _A ≤ 125°C | | Unit |
|------------------|--|--|------------------------|-----------------------|---------------|--------------------|-----------------------|--------------------|------------------------|--------------------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| V _{IH} | Minimum High-Level Input Voltage Enable/Channel Select Inputs | R _{ON} = Per Spec | 3.0 4.5 5.5 | 1.2 2.0 2.0 | | | 1.2 2.0 2.0 | | 1.2 2.0 2.0 | | V |
| V _{IL} | Maximum Low-Level Input Voltage Enable/Channel Select Inputs | R _{ON} = Per Spec | 3.0 4.5 5.5 | | | 0.53 0.8 0.8 | | 0.53 0.8 0.8 | | 0.53 0.8 0.8 | V |
| I _{IN} | Maximum Input Leakage Current Enable/Channel Select Input | V _{IN} = V _{CC} or GND | 0 to 5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current | V _{IN} = V _{CC} or GND V _{IO} = 0 V | 5.5 | | | 2.0 | | 20 | | 40 | μA |
| I _{CCT} | Quiescent Supply Current | One of Enable or Channel Select at 3.4 V, Other at V _{CC} or GND; I/O, O/I at GND | 5.5 | | | 1.35 | | 1.5 | | 1.65 | mA |
| R _{ON} | Maximum "ON" Resistance | V _{IN} = V _{IH} V _{IS} = V _{CC} to GND I _{IS} ≤ 20 mA (Figure 1) | 2.0 3.0 4.5 | | 25 12 5 | 50 20 10 | | 70 30 15 | | 100 45 25 | Ω |
| | | Endpoints V _{IN} = V _{IH} V _{IS} = V _{CC} to GND I _{IS} ≤ 20 mA (Figure 1) | 2.0 3.0 4.5 | | 25 12 5 | 50 20 10 | | 65 26 13 | | 90 40 22 | Ω |
| I _{OFF} | Maximum Off-Channel Leakage Current, Any One Channel | V _{IN} = V _{IL} V _{IO} = V _{CC} to GND Switch Off (Figure 2) | 5.5 | | | 0.1 | | 0.5 | | 1.0 | μA |
| | Maximum Off-Channel Leakage Current, Common Channel | V _{IN} = V _{IL} V _{IO} = V _{CC} to GND Switch Off (Figure 3) | 5.5 | | | 0.1 | | 1.0 | | 2.0 | μA |
| I _{ON} | Maximum On-Channel Leakage Current | V _{IN} = V _{IH} V _{IS} = V _{CC} to GND (Figure 4) | 5.5 | | | 0.1 | | 0.5 | | 1.0 | μA |

AC ELECTRICAL CHARACTERISTICS ($C_{load} = 50 \text{ pF}$, Input $t_r/t_f = 3.0 \text{ ns}$)

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = 25°C | | | T _A ≤ 85°C | | T _A ≤ 125°C | | Unit |
|--|---|---|--------------------------|-----------------------|-------------------|---------------------|-----------------------|---------------------|------------------------|----------------------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Input X to X ₀ or X ₁ | Figure 5 | 2.0 3.0 4.5 5.5 | | 1 0 0 0 | 5 2 1 1 | | 6 3 1 1 | | 7 4 2 1 | ns |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, SELECT to Analog Output | Figure 6 | 2.0 3.0 4.5 5.5 | | 15 8 6 4 | 35 15 10 7 | | 46 20 13 9 | | 57 25 17 11 | ns |
| t _{PZL} , t _{PZH} , t _{PLZ} , t _{PHZ} | Maximum Propagation Delay, ENABLE to Analog Output | R _L = 1000 Ω Figure 7 | 2.0 3.0 4.5 5.5 | | 15 8 6 4 | 35 15 10 7 | | 46 20 13 9 | | 57 25 17 11 | ns |
| C _{IN} | Maximum Input Capacitance | ON/OFF Control Input | 0.0 | | 3 | 10 | | 10 | | 10 | pF |
| | | Analog I/O (Control Input = GND) | 5.0 | | — | 35 | | 35 | | 35 | |
| | | Common I/O | | | — | 50 | | 50 | | 50 | |
| | | Feedthrough | | | — | 1.0 | | 1.0 | | 1.0 | |

| | | | |
|-----------------|--|---|----|
| C _{PD} | Power Dissipation Capacitance (per Switch) (Note 1) Figure 8 | Typical @ 25°C, V _{CC} = 5.0 V | pF |
| | | 18 | |

(1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

| Symbol | Parameter | Test Conditions | V _{CC} | Limit † 25°C | Unit |
|-----------------------|--|---|--|--|------------------|
| BW | Maximum On-Channel Bandwidth or Minimum Frequency Response Figure 9 | f _{in} = 1 MHz Sine Wave Adjust f _{in} voltage to obtain 0 dBm at V _{OS} Increase f _{in} = frequency until dB meter reads -3 dB R _L = 50 Ω, C _L = 10 pF | 3.0 4.5 5.5 | 150 175 200 | MHz |
| ISO _{off} | Off-Channel Feedthrough Isolation Figure 10 | f _{in} = Sine Wave Adjust f _{in} voltage to obtain 0 dBm at V _{IS} f _{in} = 10 kHz, R _L = 600 Ω, C _L = 50 pF f _{in} = 1.0 MHz, R _L = 50 Ω, C _L = 10 pF | 3.0 4.5 5.5 3.0 4.5 5.5 | -50 -50 -50 -40 -40 -40 | dB |
| NOISE _{feed} | Feedthrough Noise Channel Select to Switch Figure 11 | V _{in} ≤ 1 MHz Square Wave (t _r = t _f = 2 ns) Adjust R _L at setup so that I _S = 0 A R _L = 600 Ω, C _L = 50 pF R _L = 50 Ω, C _L = 10 pF | 3.0 4.5 5.5 3.0 4.5 5.5 | 45 60 100 25 30 60 | mV _{pp} |
| THD | Total Harmonic Distortion Figure 12 | f _{in} = 1 kHz, R _L = 10 kΩ, C _L = 50 pF THD = THD _{Measured} - THD _{Source} V _{IS} = 3.0 V _{pp} sine wave V _{IS} = 4.0 V _{pp} sine wave V _{IS} = 5.0 V _{pp} sine wave | 3.3 4.5 5.5 | 0.20 0.10 0.06 | % |

†Guaranteed limits not tested. Determined by design and verified by qualification.

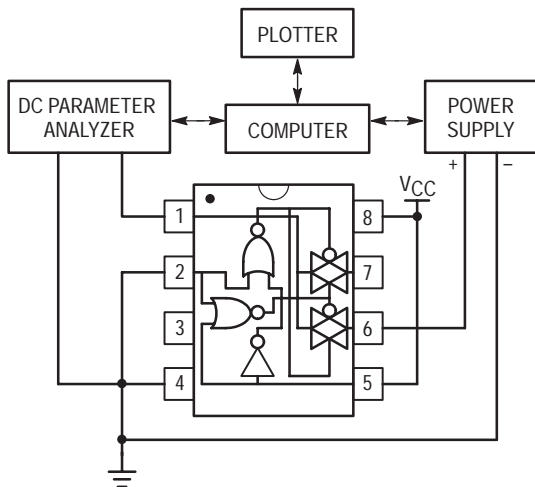


Figure 1. On Resistance Test Set-Up

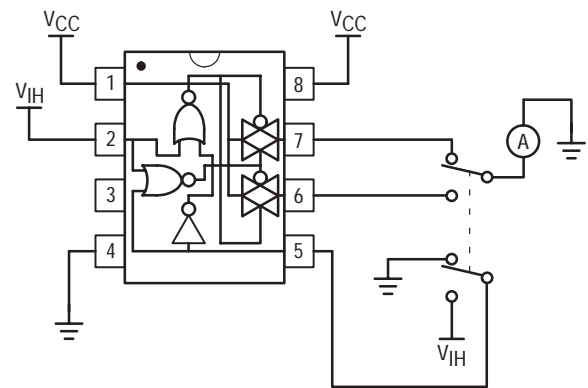


Figure 2. Maximum Off-Channel Leakage Current Test Set-Up, Any One Channel

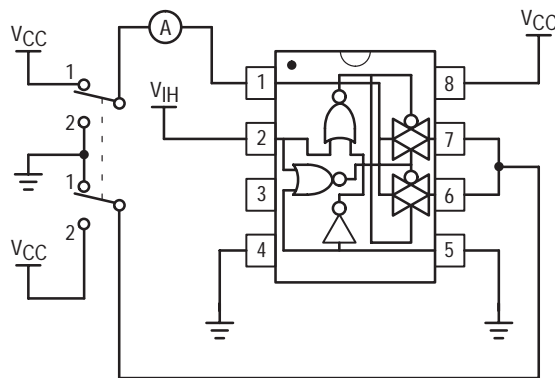


Figure 3. Maximum Off-Channel Leakage Current Test Set-Up, Common Channel

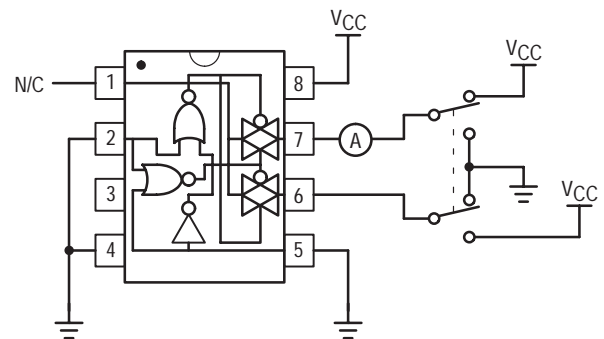


Figure 4. Maximum On-Channel Leakage Current Test Set-Up

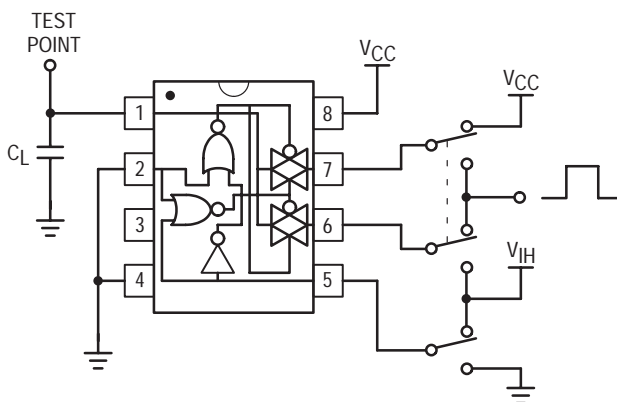


Figure 5. Propagation Delay Test Set-Up, Analog I/O to Analog I/O

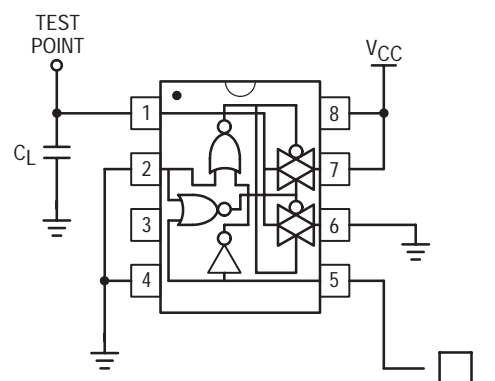


Figure 6. Propagation Delay Test Set-Up, Channel Select to Analog I/O

MC74VHC1GT53

Switch SW1 to Position 1 when testing t_{PLZ} and t_{PZL}
 Switch SW1 to Position 2 when testing t_{PHZ} and t_{PZH}
 Testing should be repeated with Switch SW2 in Position 2 to test both channels

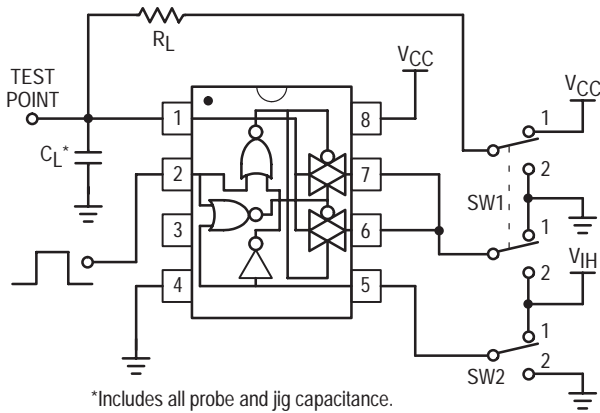


Figure 7. Propagation Delay Output Enable/Disable to Analog Output Test Set-Up

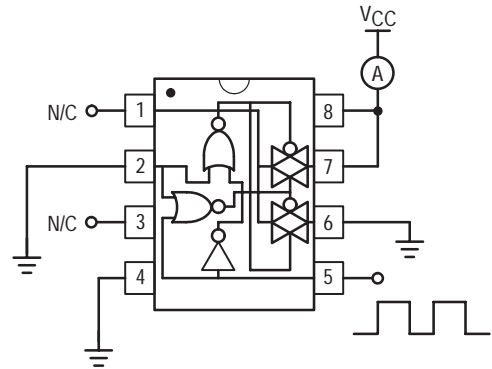


Figure 8. Power Dissipation Capacitance Test Set-Up

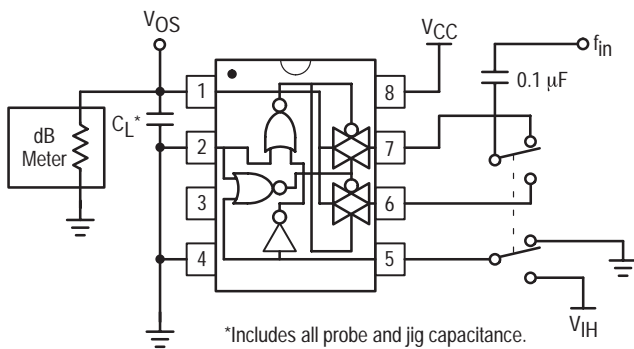


Figure 9. Maximum On-Channel Bandwidth Test Set-Up

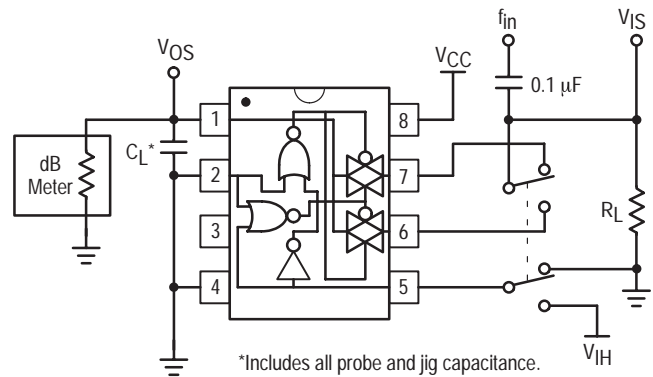


Figure 10. Off-Channel Feedthrough Isolation Test Set-Up

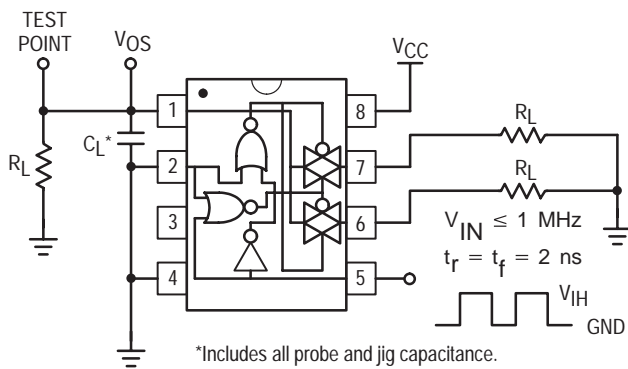


Figure 11. Feedthrough Noise, Channel Select to Analog Out, Test Set-Up

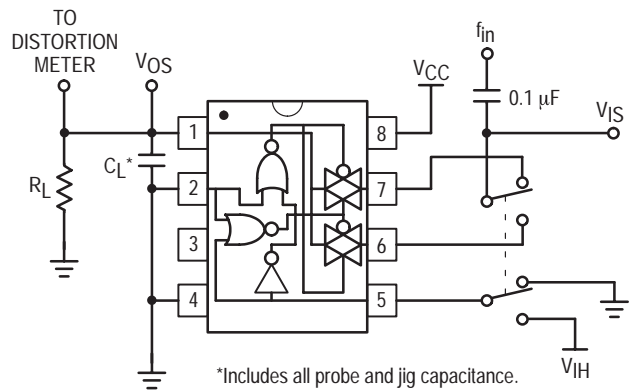


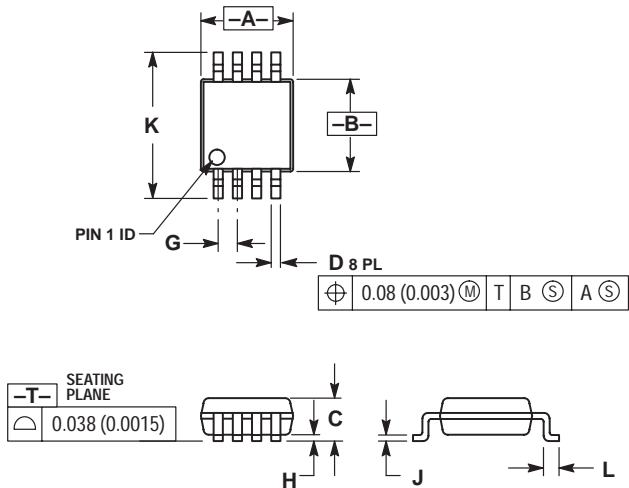
Figure 12. Total Harmonic Distortion Test Set-Up

OUTLINE DIMENSIONS

PLANNED PACKAGE

8-Lead Micro 8

T_{amb} = -55°C to 125°C



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

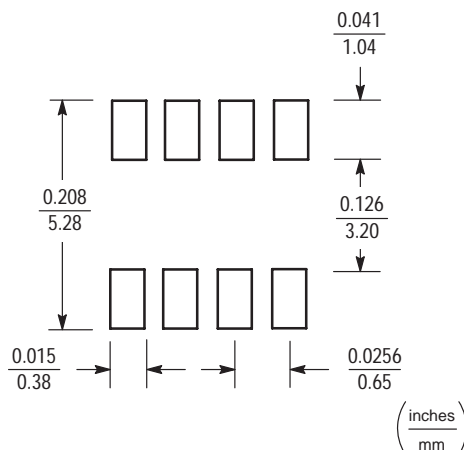
| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 2.90 | 3.10 | 0.114 | 0.122 |
| B | 2.90 | 3.10 | 0.114 | 0.122 |
| C | --- | 1.10 | --- | 0.043 |
| D | 0.25 | 0.40 | 0.010 | 0.016 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.05 | 0.15 | 0.002 | 0.006 |
| J | 0.13 | 0.23 | 0.005 | 0.009 |
| K | 4.75 | 5.05 | 0.187 | 0.199 |
| L | 0.40 | 0.70 | 0.016 | 0.028 |

INFORMATION FOR USING THE Micro8 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to ensure proper solder connection interface

between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process.



Micro8 POWER DISSIPATION

The power dissipation of the Micro8 is a function of the input pad size. This can vary from the minimum pad size for soldering to the pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient; and the operating temperature, T_A . Using the values provided on the data sheet for the Micro8 package, P_D can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into

the equation for an ambient temperature T_A of 25°C, one can calculate the power dissipation of the device which in this case is 300 mW.

$$P_D = \frac{100^\circ\text{C} - 25^\circ\text{C}}{250^\circ\text{C/W}} = 300 \text{ mW}$$

The 250°C/W for the Micro8 package assumes the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 300 mW using the footprint shown. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using board material such as Thermal Clad, the power dissipation can be doubled using the same footprint.

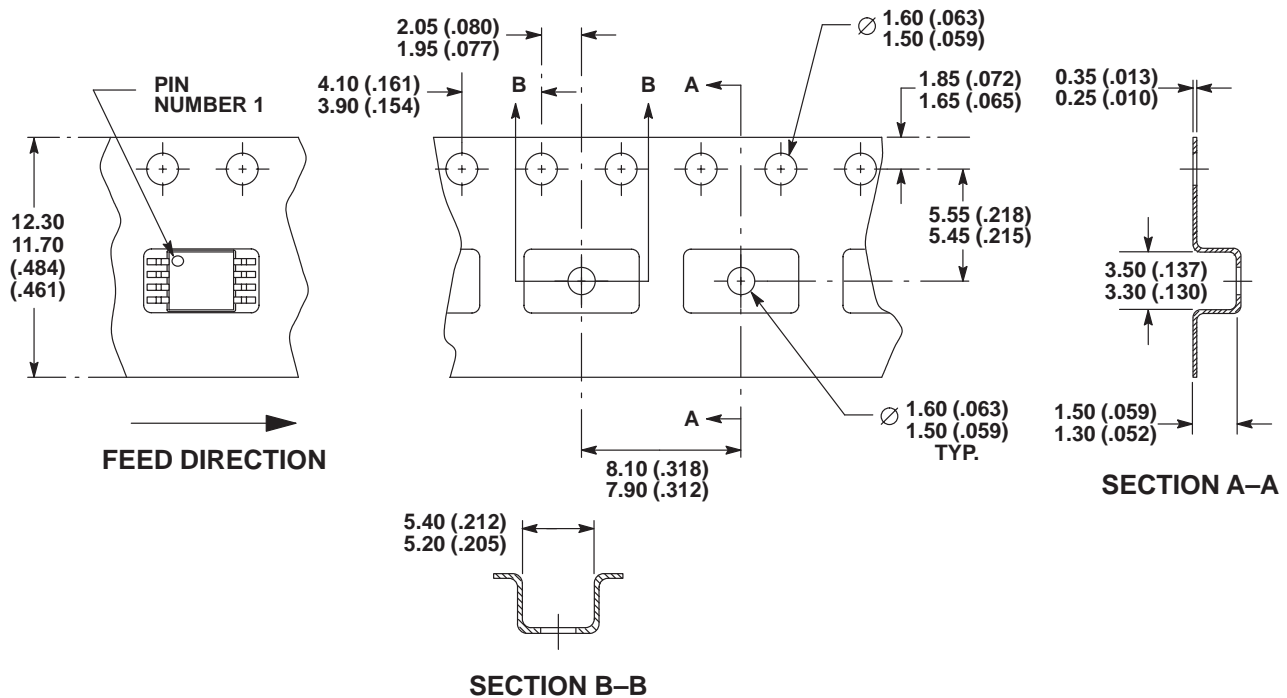
SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

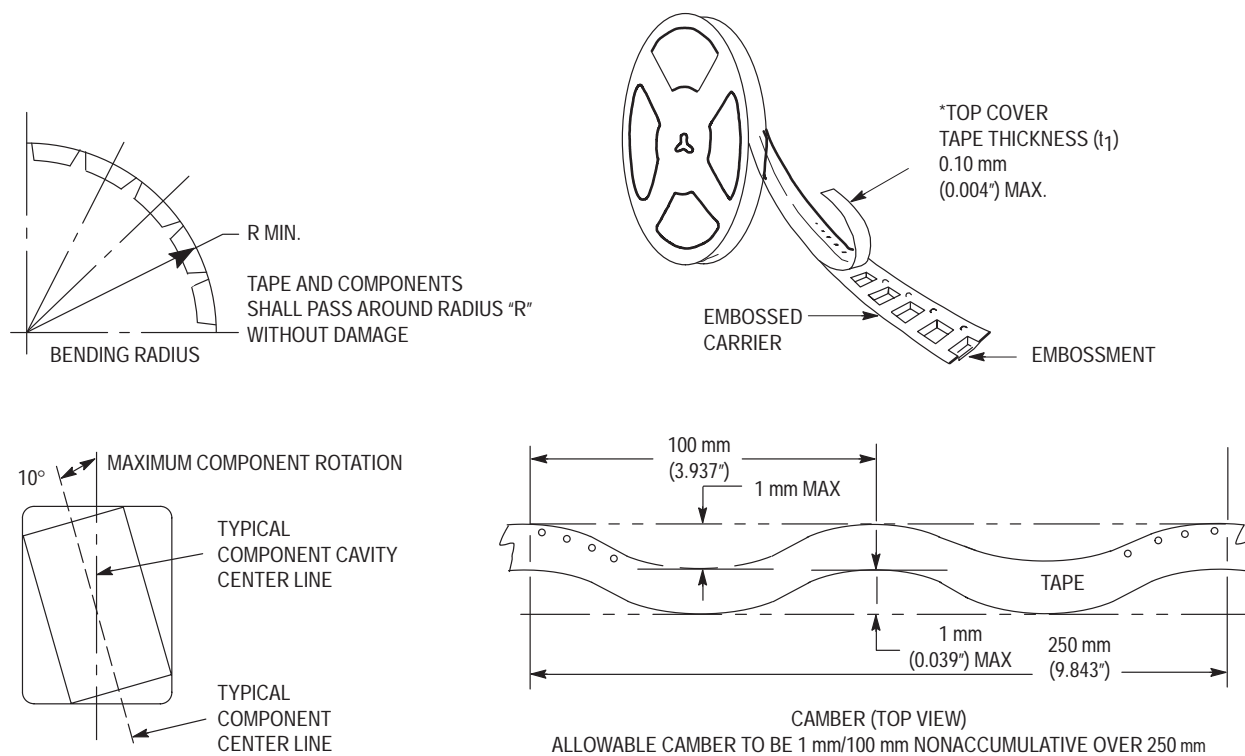
- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

**NOTES:**

1. CONFORMS TO EIA-481-1.
2. CONTROLLING DIMENSION: MILLIMETER.

**Figure 13. Carrier Tape Specifications**

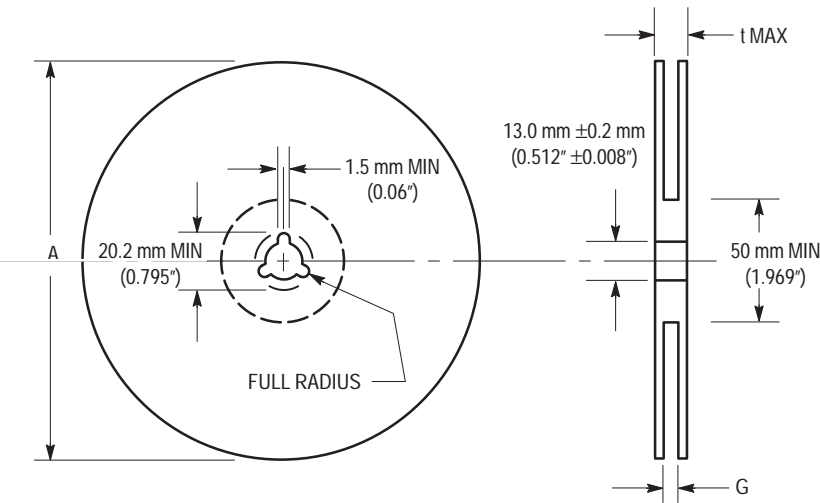


Figure 14. Reel Dimensions

REEL DIMIENSIONS

| Tape Size | A Max | G | t Max |
|-----------|---------------------|---|--------------------|
| 12 mm | 330 mm (12.992") | 12.4 mm, +2.0 mm, -0.0 (0.49", +0.079", -0.00) | 18.4 mm (0.72") |

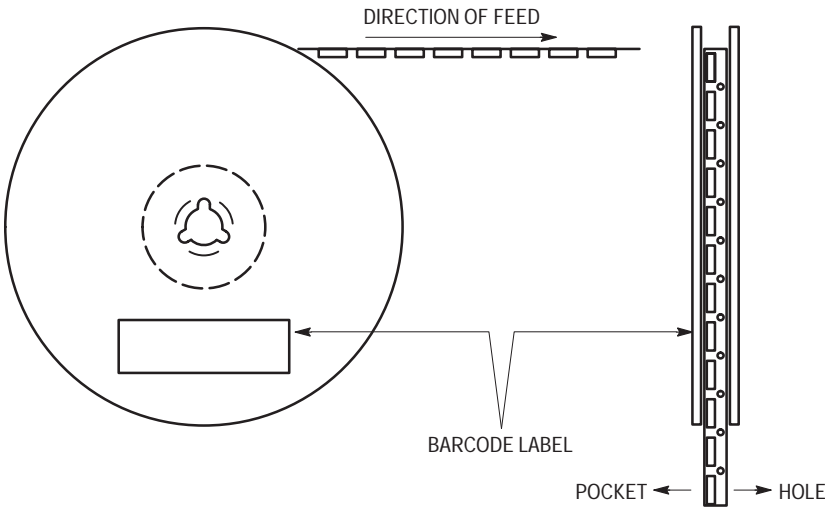


Figure 15. Reel Winding Direction

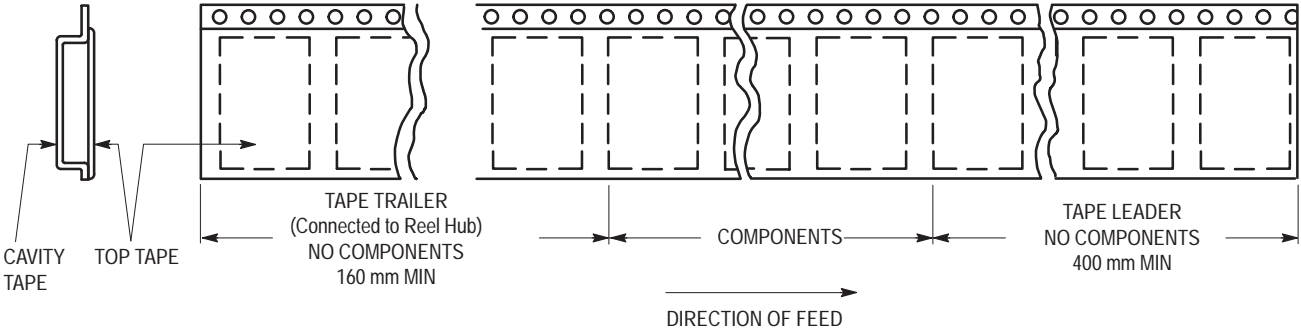



Figure 16. Tape Ends for Finished Goods

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